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AUTOMOTIVE, 105°C OPERATION, LOW INPUT OFFSET VOLTAGE CMOS OPERATIONAL AMPLIFIER

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This IC incorporates a general purpose analog circuit in a small package. This is a zero-drift operational amplifier with Rail-to-Rail input and output, which uses auto-zeroing techniques to provide low input offset voltage.

This IC is suitable for applications requiring less offset voltage.

The S-19611AB is a dual operational amplifier (2 circuits).

Caution This product can be used in vehicle equipment and in-vehicle equipment. Before using the product for these purposes, it is imperative to contact our sales representatives.

■ Features

• Low input offset voltage: $V_{IO} = +17 \,\mu\text{V} \text{ max.}$ (Ta = +25°C)

 $V_{IO} = +100 \,\mu V \text{ max.}$ (Ta = -40°C to +105°C)

Operation power supply voltage range: V_{DD} = 2.65 V to 5.50 V
 Low current consumption (Per circuit): I_{DD} = 200 μA typ.

• Internal phase compensation: No external parts required

• Rail-to-Rail input and output

• Operation temperature range: Ta = -40°C to +105°C

• Lead-free (Sn 100%), halogen-free

AEC-Q100 qualified*1

■ Applications

- High-accuracy current detection
- · Various sensor interfaces
- Strain gauge amplifier

■ Package

• TMSOP-8

^{*1.} Contact our sales representatives for details.

■ Block Diagram

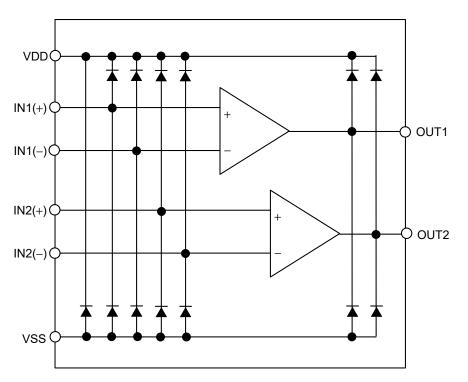


Figure 1

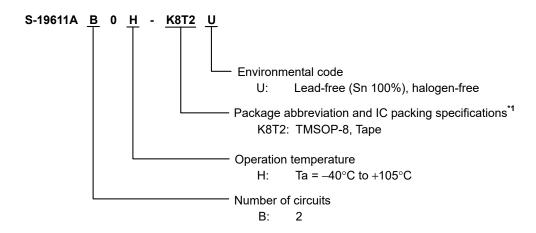
■ AEC-Q100 Qualified

This IC supports AEC-Q100 for the operation temperature grade 2. Contact our sales representatives for details of AEC-Q100 reliability specification.

■ Product Name Structure

Refer to "1. Product name" regarding the contents of product name, "2. Package" regarding the package drawings and "3. Product name list" regarding the product type.

1. Product name



*1. Refer to the tape drawing.

2. Package

Table 1 Package Drawing Codes

Package Name	Dimension	Tape	Reel
TMSOP-8	FM008-A-P-SD	FM008-A-C-SD	FM008-A-R-SD

3. Product name list

Table 2

Product Name	Package		
S-19611AB0H-K8T2U	TMSOP-8		

■ Pin Configuration

1. TMSOP-8

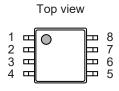


Figure 2

Table 3

Pin No.	Symbol	Description
1	OUT1	Output pin 1
2	IN1(-)	Inverted input pin 1
3	IN1(+)	Non-inverted input pin 1
4	VSS	GND pin
5	IN2(+)	Non-inverted input pin 2
6	IN2(-)	Inverted input pin 2
7	OUT2	Output pin 2
8	VDD	Positive power supply pin

■ Absolute Maximum Ratings

Table 4

(Ta = -40°C to +105°C unless otherwise specified)

Item	Symbol	Absolute Maximum Rating	Unit
Power supply voltage	V _{DD}	$V_{SS} - 0.3$ to $V_{SS} + 6.0$	V
Input voltage	$V_{IN(+)}$, $V_{IN(-)}$	$V_{SS}-0.3$ to $V_{DD}+0.3$	V
Output voltage	Vout	$V_{SS} - 0.3$ to $V_{DD} + 0.3$	V
Differential input voltage	V _{IND}	±5.5	V
Output pip ourrent	ISOURCE	10.0	mA
Output pin current	Isink	10.0	mA
Operation ambient temperature	Topr	-40 to +105	°C
Storage temperature	T _{stg}	−55 to +125	°C

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.

■ Thermal Resistance Value

Table 5

Item	Symbol	l Condition		Min.	Тур.	Max.	Unit
Junction-to-ambient thermal resistance*1	θја	TMSOP-8	Board A	_	160	_	°C/W
			Board B	_	133	_	°C/W
			Board C	_	_	-	°C/W
			Board D	_	_	-	°C/W
			Board E	_	_	_	°C/W

^{*1.} Test environment: compliance with JEDEC STANDARD JESD51-2A

Remark Refer to "■ Power Dissipation" and "Test Board" for details.

■ Electrical Characteristics

1. Recommended operation condition

Table 6

(Ta = -40°C to +105°C unless otherwise specified)

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Item	Symbol	Condition	Min.	Тур.	Max.	Unit	Test Circuit
Operation power supply voltage range	V _{DD}	-	2.65	5.00	5.50	V	1

2. $V_{DD} = 5.0 \text{ V}$

Table 7

DC Electrical Characteristics		(Ta	= -40°C to	+105°C	unless othe	rwise s	oecified)
Item	Symbol	Condition	Min.	Тур.	Max.	Unit	Test Circuit
Current consumption (2 circuits)	I _{DD}	$V_{CMR} = V_{OUT} = \frac{V_{DD}}{2}$	_	400	600	μΑ	5
logue offeet veltere	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	$V_{CMR} = \frac{V_{DD}}{2}$, $Ta = +25$ °C	-17	±1	+17	μV	1
Input offset voltage	V _{IO}	$V_{CMR} = \frac{V_{DD}}{2}$	-100	±1	+100	μV	1
Input offset voltage drift	$\frac{\Delta V_{IO}}{\Delta Ta}$	$V_{CMR} = \frac{V_{DD}}{2}$	-	±0.1	_	μV/°C	1
Input bigg current	laa	Ta = +25°C	_	±70	_	pА	_
Input bias current	IBIAS	_	_	±3000	_	pА	_
land to effect accompany	lio	Ta = +25°C	_	±140	_	pА	_
Input offset current	110	_	_	±300	_	pА	_
Common-mode input voltage range	V _{CMR}	-	Vss - 0.1	_	V _{DD} + 0.1	٧	2
Voltage gain (open loop)	Avol	$\begin{split} V_{SS} + 0.1 & V \leq V_{OUT} \leq V_{DD} - 0.1 & V, \\ V_{CMR} = \frac{V_{DD}}{2}, & R_L = 10 & k\Omega \end{split}$	106	130	-	dB	8
M	Vон	$R_L = 10 \text{ k}\Omega$	4.9	ı	_	V	3
Maximum output swing voltage	VoL	$R_L = 10 \text{ k}\Omega$	-	1	0.1	V	4
Common-mode input signal rejection ratio	CMRR	$V_{SS} - 0.1 \ V \le V_{CMR} \le V_{DD} + 0.1 \ V$	100	130	-	dB	2
Power supply voltage rejection ratio	PSRR	$2.65 \text{ V} \le V_{DD} \le 5.50 \text{ V}$	95	120	_	dB	1
Source current	Isource	$V_{OUT} = V_{DD} - 0.1 V$	0.8	2.5	-	mA	6
Sink current	Isink	V _{OUT} = 0.1 V	1.0	2.9	-	mA	7

Table 8

AC Electrical Characteristics			$a = -40^{\circ}$ C to +	105°C unies	ss otnerwise	specified)
Item	Symbol	Condition	Min.	Тур.	Max.	Unit
Slew rate	ISR	$R_L = 1.0 \text{ M}\Omega$, $C_L = 15 \text{ pF}$ (Refer to Figure 11)	_	0.22	-	V/μs
Gain-bandwidth product	GBP	C _L = 0 pF	_	320	_	kHz

■ Test Circuits (Per circuit)

1. Power supply voltage rejection ratio, input offset voltage

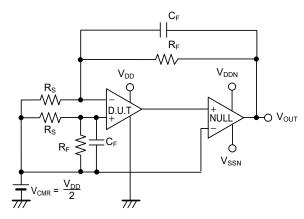


Figure 3 Test Circuit 1

• Power supply voltage rejection ratio (PSRR)

The power supply voltage rejection ratio (PSRR) can be calculated by the following expression, with V_{OUT} measured at each V_{DD} .

Test conditions:

$$V_{DD} = 2.65 \text{ V}$$
: $V_{DD} = V_{DD1}$, $V_{OUT} = V_{OUT1}$
 $V_{DD} = 5.50 \text{ V}$: $V_{DD} = V_{DD2}$, $V_{OUT} = V_{OUT2}$

$$PSRR = 20 log \left(\left| \frac{V_{DD1} - V_{DD2}}{\left(V_{OUT1} - \frac{V_{DD1}}{2}\right) - \left(V_{OUT2} - \frac{V_{DD2}}{2}\right)} \right| \times \frac{R_F + R_S}{R_S} \right)$$

• Input offset voltage (V_{IO})

$$V_{IO} = \left(V_{OUT} - \frac{V_{DD}}{2}\right) \times \frac{R_S}{R_F + R_S}$$

2. Common-mode input signal rejection ratio, common-mode input voltage range

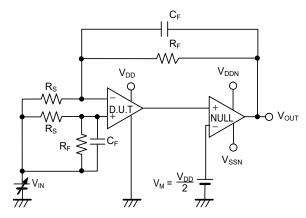


Figure 4 Test Circuit 2

• Common-mode input signal rejection ratio (CMRR)

The common-mode input signal rejection ratio (CMRR) can be calculated by the following expression, with V_{OUT} measured at each V_{IN} .

Test conditions:

$$V_{IN} = V_{CMR Max.}$$
: $V_{IN} = V_{IN1}$, $V_{OUT} = V_{OUT1}$
 $V_{IN} = V_{CMR Min.}$: $V_{IN} = V_{IN2}$, $V_{OUT} = V_{OUT2}$

$$CMRR = 20 log \left(\left| \frac{V_{IN1} - V_{IN2}}{(V_{OUT1} - V_{IN1}) - (V_{OUT2} - V_{IN2})} \right| \times \frac{R_F + R_S}{R_S} \right)$$

• Common-mode input voltage range (V_{CMR})

The common-mode input voltage range is the range of V_{IN} in which V_{OUT} satisfies the common-mode input signal rejection ratio specifications when V_{IN} is changed.

3. Maximum output swing voltage

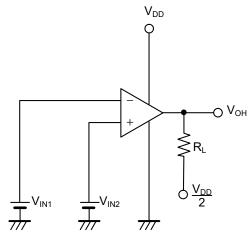


Figure 5 Test Circuit 3

• Maximum output swing voltage (VoH)

Test conditions:

$$V_{\text{IN1}} = \frac{V_{\text{DD}}}{2} - 0.1 \text{ V}$$

$$V_{\text{IN2}} = \frac{V_{\text{DD}}}{2} + 0.1 \text{ V}$$

$$R_{\text{L}} = 10 \text{ k}\Omega$$

$$V_{IN2} = \frac{V_{DD}}{2} + 0.1 \text{ V}$$

4. Maximum output swing voltage

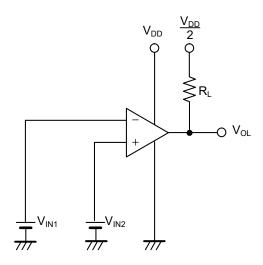


Figure 6 Test Circuit 4

• Maximum output swing voltage (VoL)

Test conditions:

$$V_{IN1} = \frac{V_{DD}}{2} + 0.1$$

$$V_{\text{IN1}} = \frac{V_{\text{DD}}}{2} + 0.1 \text{ V}$$

$$V_{\text{IN2}} = \frac{V_{\text{DD}}}{2} - 0.1 \text{ V}$$

$$R_{\text{L}} = 10 \text{ k}\Omega$$

5. Current consumption

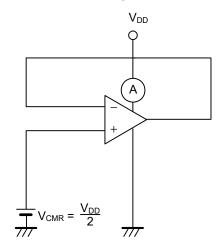


Figure 7 Test Circuit 5

6. Source current

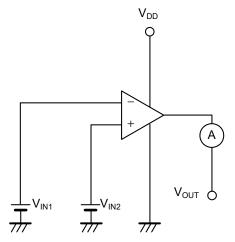


Figure 8 Test Circuit 6

• Current consumption (IDD)

• Source current (I_{SOURCE})

Test conditions: $V_{OUT} = V_{DD} - 0.1 \text{ V}$ $V_{IN1} = \frac{V_{DD}}{2} - 0.1 \text{ V}$ $V_{IN2} = \frac{V_{DD}}{2} + 0.1 \text{ V}$

7. Sink current

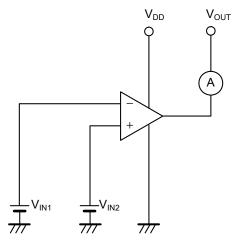


Figure 9 Test Circuit 7

• Sink current (Isink)

Test conditions: $V_{OUT} = 0.1 \text{ V}$ $V_{IN1} = \frac{V_{DD}}{2} + 0.1 \text{ V}$ $V_{IN2} = \frac{V_{DD}}{2} - 0.1 \text{ V}$

8. Voltage gain

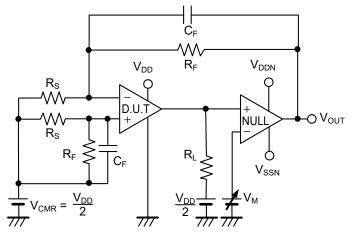


Figure 10 Test Circuit 8

• Voltage gain (open loop) (Avol)

The voltage gain (A_{VOL}) can be calculated by the following expression, with V_{OUT} measured at each V_{M} .

Test conditions:

$$V_M = V_{DD} - 0.1 \ V$$
: $V_M = V_{M1}, \ V_{OUT} = V_{OUT1}$
 $V_M = 0.1 \ V$: $V_M = V_{M2}, \ V_{OUT} = V_{OUT2}$

$$A_{VOL} = 20 log \left(\left| \frac{V_{M1} - V_{M2}}{V_{OUT1} - V_{OUT2}} \right| \times \frac{R_F + R_S}{R_S} \right)$$

$$R_L = 10 k\Omega$$

 $V_{DD} \times 0.1$

9. Slew rate

 $(= V_{IN(-)})$

Measured by the voltage follower circuit.

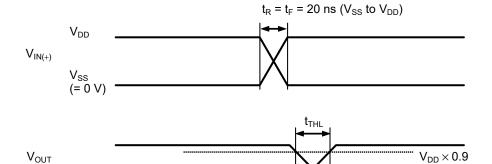


Figure 11

 t_{TLH}

• Slew rate (SR)

When falling
$$SR = \frac{V_{DD} \times 0.8}{t_{THL}}$$

When rising
$$SR = \frac{V_{DD} \times 0.8}{t_{TLH}}$$

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■ Usage Examples

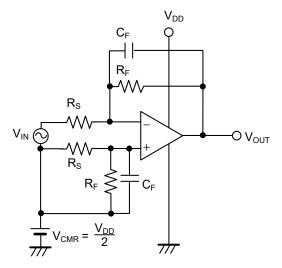


Figure 12 Differential Amplifier Circuit

[Example of Gain = 1000 times]

 $R_S = 1 k\Omega$

 $R_F = 1 M\Omega$

 $C_F = 1000 pF$

[Example of Gain = 100 times]

 $R_S = 1 k\Omega$

 R_F = 100 $k\Omega$

 $C_F = 1000 pF$

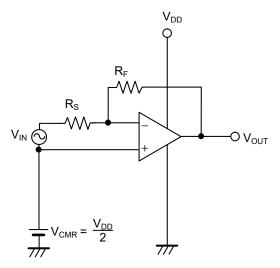


Figure 13 Inverting Amplifier Circuit

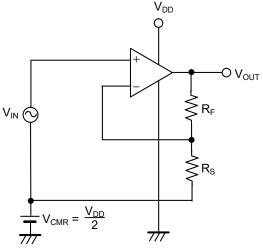


Figure 14 Non-inverting Amplifier Circuit

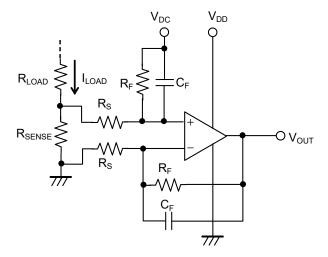


Figure 15 Low-side Current Detection Circuit

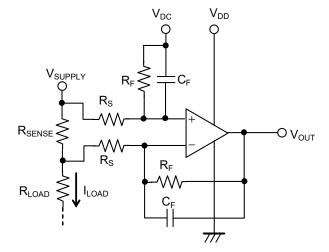


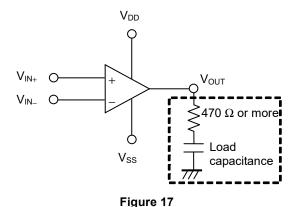
Figure 16 High-side Current Detection Circuit

Caution The above connection diagrams and constants will not guarantee successful operation.

Perform thorough evaluation using the actual application to set the constants.

■ Precautions

- During the operation of an operational amplifier circuit, when V_{OUT} ≤ V_{SS} + 100 mV or V_{OUT} ≥ V_{DD} 100 mV, the signal becomes difficult to be output, and the output voltage (V_{OUT}) may become V_{SS} or V_{DD}. If this happens, supply an appropriate input signal to the operational amplifier so that V_{OUT} is within the range of V_{SS} + 100 mV to V_{DD} 100 mV. Contact our sales representatives if you have any questions for use in the above operation conditions.
- Generally an operational amplifier may cause oscillation depending on the selection of external parts. Perform thorough evaluation using the actual application to set the constant.
- Do not apply an electrostatic discharge to this IC that exceeds performance ratings of the built-in electrostatic protection circuit.
- ABLIC Inc. claims no responsibility for any disputes arising out of or in connection with any infringement by products including this IC of patents owned by a third party.
- Use this IC with the output current of 10 mA or less.
- When using the voltage follower circuit (Gain = 1 time), connect a resistor of 470 Ω or more for the stable operation as shown in **Figure 17**. The operation may become unstable depending on the value of the load capacitance connected to the output pin, even when the voltage follower circuit is not used. Use the product under thorough evaluation.



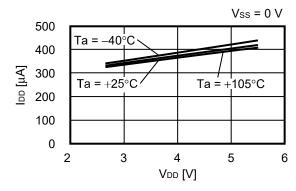
Caution The above connection diagram and constant will not guarantee successful operation.

Perform thorough evaluation using the actual application to set the constant.

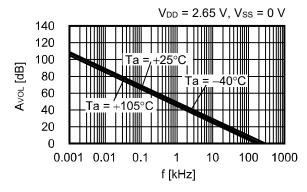
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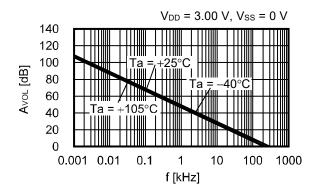
■ Characteristics (Typical Data)

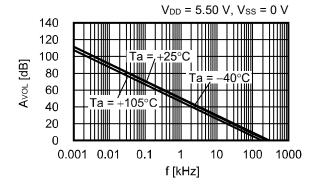
1. Current consumption (IDD) (2 circuits) vs. Power supply voltage (VDD)



2. Voltage gain (AvoL) vs. Frequency (f)

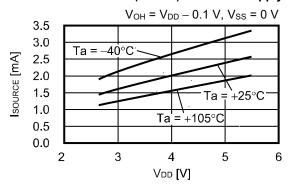




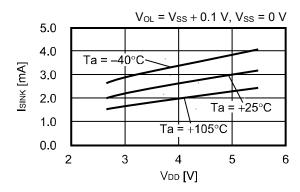


3. Output current

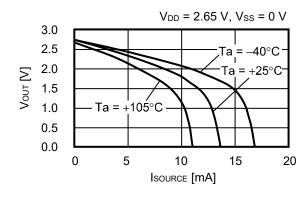
3. 1 Source current (Isource) vs. Power supply voltage (VDD)

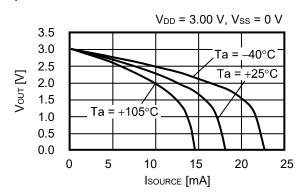


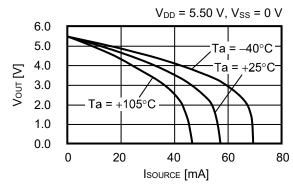
3. 2 Sink current (ISINK) vs. Power supply voltage (VDD)



3. 3 Output voltage (Vout) vs. Source current (Isource)

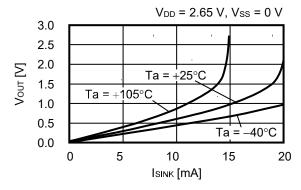


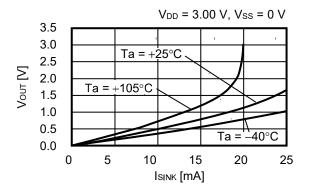


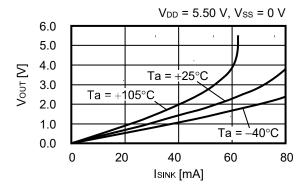


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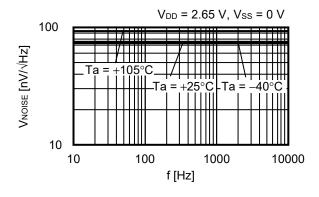
3. 4 Output voltage (Vout) vs. Sink current (Isink)

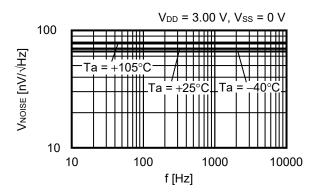


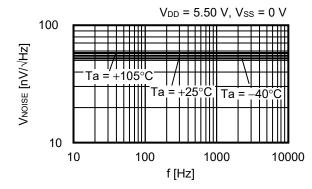




4. Input noise voltage density (V_{NOISE}) vs. Frequency (f)

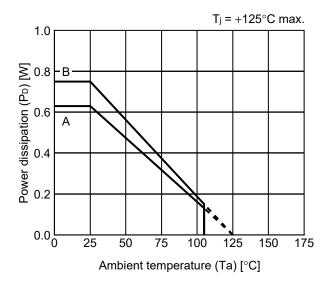






■ Power Dissipation

TMSOP-8



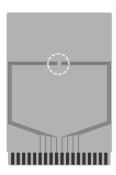
Board	Power Dissipation (P _D)
Α	0.63 W
В	0.75 W
С	_
D	_
E	_

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TMSOP-8 Test Board

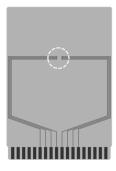
(1) Board A





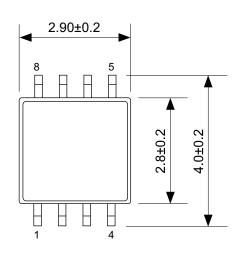
Item		Specification
Size [mm]		114.3 x 76.2 x t1.6
		FR-4
Number of copper foil layer		2
	1	Land pattern and wiring for testing: t0.070
Copper foil layer [mm]	2	-
Copper foil layer [min]	3	-
	4	74.2 x 74.2 x t0.070
Thermal via		-

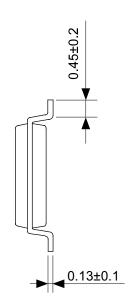
(2) Board B

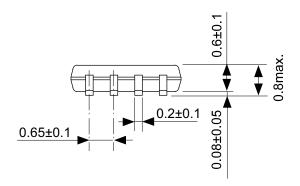


Item		Specification
Size [mm]		114.3 x 76.2 x t1.6
Material		FR-4
Number of copper foil layer		4
	1	Land pattern and wiring for testing: t0.070
Connor foil lover [mm]	2	74.2 x 74.2 x t0.035
Copper foil layer [mm]	3	74.2 x 74.2 x t0.035
	4	74.2 x 74.2 x t0.070
Thermal via		-

No. TMSOP8-A-Board-SD-1.0

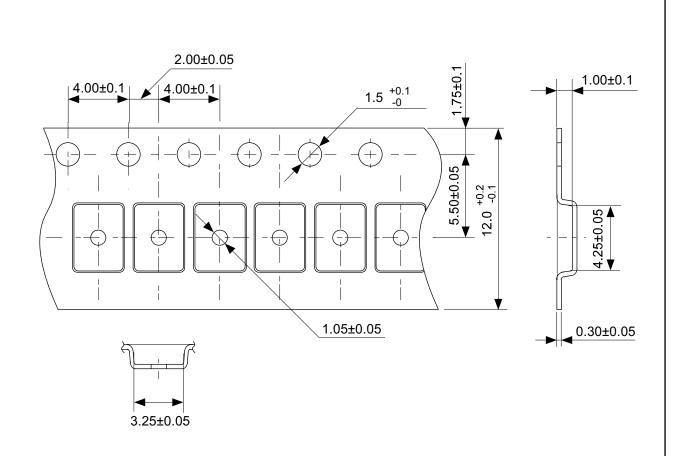


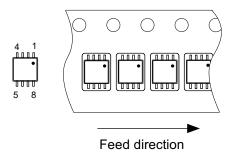




No. FM008-A-P-SD-1.2

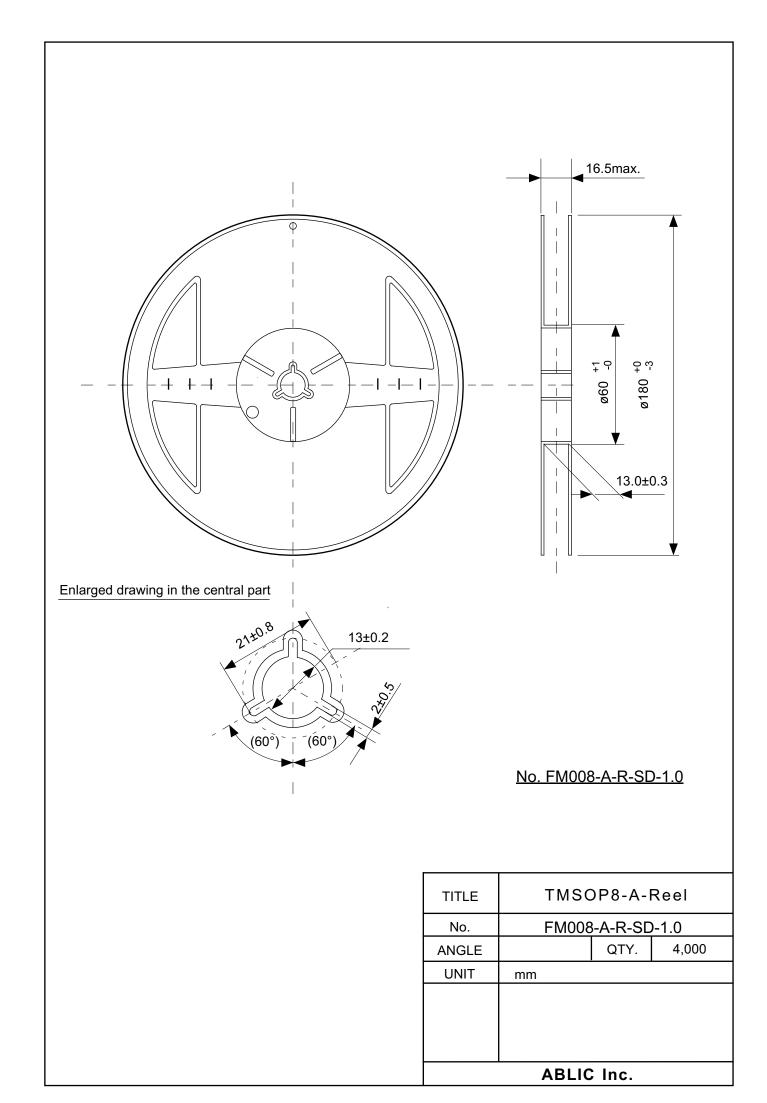
TITLE	TMSOP8-A-PKG Dimensions			
No.	FM008-A-P-SD-1.2			
ANGLE	O			
UNIT	mm			
ABLIC Inc.				
ABLIC IIIC.				





No. FM008-A-C-SD-2.0

TITLE	TMSOP8-A-Carrier Tape
No.	FM008-A-C-SD-2.0
ANGLE	
UNIT	mm
ABLIC Inc.	



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